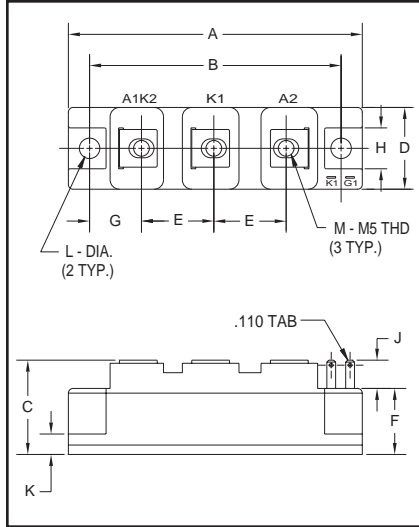


**SCR/Diode
POW-R-BLOK™ Modules
25 Amperes/1200-1600 Volts**



Outline Drawing

Dimension	Inches	Millimeters
A	3.681 Max.	93.5 Max.
B	3.150	80
C	1.181 Max.	30 Max.
D	1.024 Max.	26 Max.
E	0.906	23
F	0.827	21
G	0.650	16.5
H	0.512	13
J	0.354	9
K	0.256	6.5
L	0.256 Dia.	Dia. 6.5
M	M5 Metric	M5



**CM4212A2, CM4216A2
SCR/Diode
POW-R-BLOK™ Modules
25 Amperes/1200-1600 Volts**

Description:

Powerex SCR/Diode POW-R-BLOK™ Modules are designed for use in applications requiring Half-Control and isolated packaging. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- Isolated Mounting
- Glass Passivated Chips
- Metal Baseplate
- Low Thermal Impedance

Applications:

- Battery Supplies
- Bridge Circuits
- AC and DC Motor Control
- Tap Changers
- Lighting Control

Ordering Information:

Select the complete eight digit module part number you desire from the table below. Example: CM4212A2 is a 1200 Volt, 25 Ampere SCR/Diode POW-R-BLOK™ Module.

Type	Voltage Volts (x100)	Current Rating Amperes (25)
CM42	12 16	A2



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CM4212A2, CM4216A2
SCR/Diode POW-R-BLOK™ Modules
 25 Amperes/1200-1600 Volts

Absolute Maximum Ratings

Characteristics	Symbol	CM4212A2	CM4216A2	Units
Peak Forward Blocking Voltage	V_{DRM}	1200	1600	Volts
Transient Peak Forward Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{DSM}	1350	1700	Volts
DC Forward Blocking Voltage	$V_{D(DC)}$	960	1280	Volts
Peak Reverse Blocking Voltage	V_{RRM}	1200	1600	Volts
Transient Peak Reverse Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{RSM}	1350	1700	Volts
DC Reverse Blocking Voltage	$V_{R(DC)}$	960	1280	Volts
RMS On-State Current	$I_{T(RMS)}, I_{F(RMS)}$	39	39	Amperes
Average On-State Current, $T_C = 87^\circ C$	$I_{T(AV)}, I_{F(AV)}$	25	25	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}, I_{FSM}	490	490	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}, I_{FSM}	445	445	Amperes
I^2t (for Fusing), 8.3 milliseconds	I^2t	1000	1000	A^2sec
Critical Rate-of-Rise of On-State Current*	di/dt	100	100	Amperes/ μs
Peak Gate Power Dissipation	P_{GM}	5.0	5.0	Watts
Average Gate Power Dissipation	$P_{G(AV)}$	0.5	0.5	Watts
Peak Forward Gate Voltage	V_{GFM}	10	10	Volts
Peak Reverse Gate Voltage	V_{GRM}	5.0	5.0	Volts
Peak Forward Gate Current	I_{GFM}	2.0	2.0	Amperes
Storage Temperature	T_{STG}	-40 to 125	-40 to 125	$^\circ C$
Operating Temperature	T_j	-40 to 125	-40 to 125	$^\circ C$
Maximum Mounting Torque M6 Mounting Screw	—	26	26	in.-lb.
Maximum Mounting Torque M5 Terminal Screw	—	17	17	in.-lb.
Module Weight (Typical)	—	160	160	Grams
V Isolation	V_{RMS}	2500	2500	Volts

* $T_j = 125^\circ C, I_G = 0.5A, V_D = 1/2 V_{DRM}$



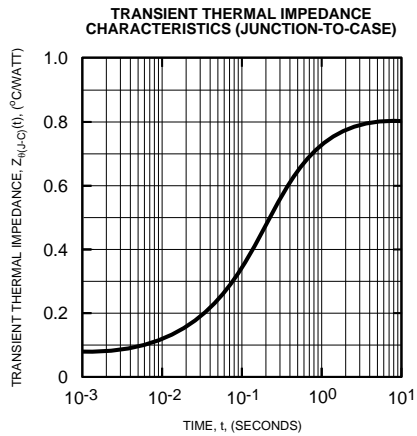
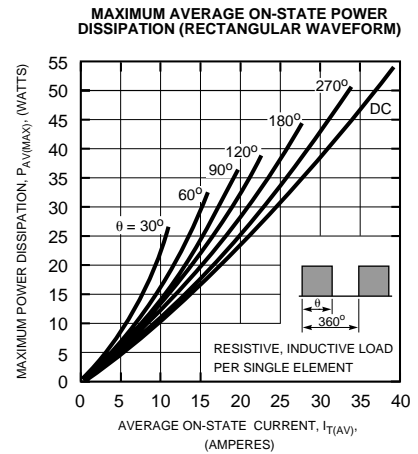
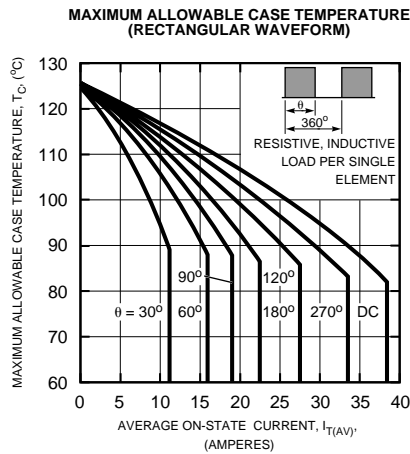
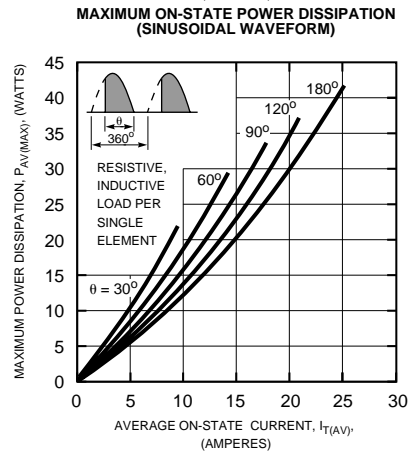
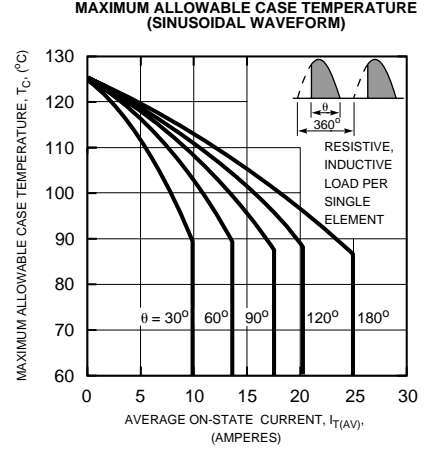
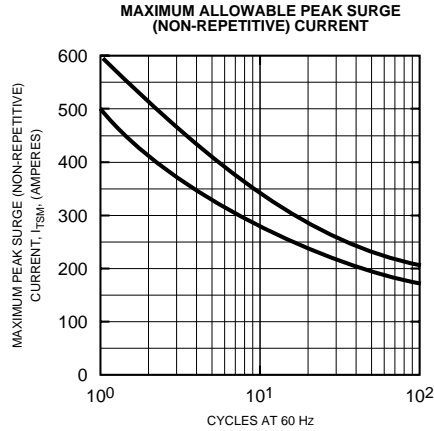
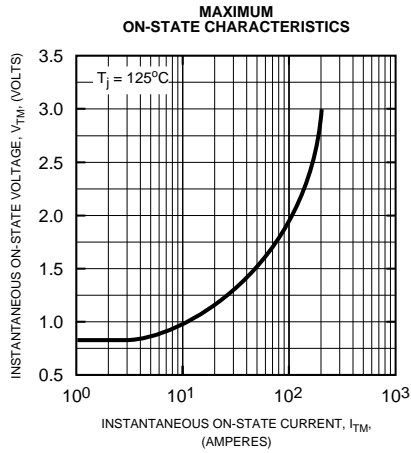
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CM4212A2, CM4216A2
SCR/Diode POW-R-BLOK™ Modules
25 Amperes/1200-1600 Volts

Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	CM4212A2/CM4216A2	Units
Blocking State Maximums				
Forward Leakage Current, Peak	I_{DRM}	$T_j = 125^\circ\text{C}$, $V_{\text{DRM}} = \text{Rated}$	10	mA
Reverse Leakage Current, Peak	I_{RRM}	$T_j = 125^\circ\text{C}$, $V_{\text{RRM}} = \text{Rated}$	10	mA
Conducting State Maximums				
Peak On-State Voltage	V_{FM} , V_{TM}	$I_{\text{FM}} = 75\text{A}$, $I_{\text{TM}} = 75\text{A}$	1.8	Volts
Switching Minimums				
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ\text{C}$, $V_{\text{D}} = 2/3 V_{\text{DRM}}$	500	Volts/ μs
Thermal Maximums				
Thermal Resistance, Junction-to-Case	$R_{\theta(\text{J-C})}$	Per Module	0.8	$^\circ\text{C/Watt}$
Thermal Resistance, Case-to-Sink (Lubricated)	$R_{\theta(\text{C-S})}$	Per Module	0.2	$^\circ\text{C/Watt}$
Gate Parameters Maximums				
Gate Current-to-Trigger	I_{GT}	$V_{\text{D}} = 6\text{V}$, $R_{\text{L}} = 2\Omega$	50	mA
Gate Voltage-to-Trigger	V_{GT}	$V_{\text{D}} = 6\text{V}$, $R_{\text{L}} = 2\Omega$	3.0	Volts
Non-Trigging Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}$, $V_{\text{D}} = 1/2 V_{\text{DRM}}$	0.25	Volts

CM4212A2, CM4216A2
SCR/Diode POW-R-BLOK™ Modules
 25 Amperes/1200-1600 Volts





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